# Low Power Oscillator for High Frequency Applications



### ■ Features, Benefits and Applications

- Lowest power, high frequency oscillator with 6.3 mA typical active current
- 125MHz to 150MHz frequency range
- LVCMOS/LVTTL compatible output
- Excellent frequency stability over temperature, ±20 PPM
- Ultra low standby current, 1.2 µA
- Standby or output enable modes
- Four industry-standard packages: 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 mm
- Drop-in replacement of quartz
- Ultra short lead time
- All-silicon device with outstanding reliability of 2 FIT (10x improvement over quartz-based devices), enhancing system mean-time-to-failure (MTBF)
- Ideal for high frequency applications in networking, storage, computer servers and communications
- Ideal for high speed protocals: GPON, EPON, Ethernet, SATA/SAS, DDR, PCI

### ■ Specifications

### **Electrical Characteristics**

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Output Frequency Range	f	125	-	150	MHz		
Frequency Stability	F_stab	-20	_	+20	PPM	Inclusive of: Initial stability, operating temperature, rated power,	
		-25	-	+25	PPM	supply voltage change, load change, shock and vibration	
		-50	-	+50	PPM	± 20 PPM available in extended commercial temperature only	
Aging	Ag	-1.0	-	1.0	PPM	1st year at 25℃	
Operating Temperature Range	T_use	-20	_	+70	∞	Extended Commercial	
		-40	_	+85	∞	Industrial	
Supply Voltage	Vdd	2.25	2.5	2.75	V		
		2.52	2.8	3.08	V		
		2.97	3.3	3.63	V	7	
Current Consumption	Idd	_	6.7	8	mA	No load condition, f = 125 MHz, Vdd = 3.3 V	
		_	6.2	7	mA	No load condition, f = 125 MHz, Vdd = 2.5 V or 2.8 V	
Standby Current	I_std	_	2.4	4.3	μΑ	ST = GND, Vdd = 3.3 V, Output is Weakly Pulled Down	
		_	1.2	2.2	μΑ	ST = GND, Vdd = 2.5 or 2.8 V, Output is Weakly Pulled Down	
Duty Cycle	DC	40	50	60	%	All Vdds	
Rise/Fall Time	Tr, Tf	_	1	2	ns	20% - 80% Vdd=2.5 V, 2.8 V or 3.3 V, 15 pf load	
Output Voltage High	VOH	90%	-	-	Vdd	IOH = -4 mA (Vdd = 3.3 V) IOH = -3 mA (Vdd = 2.8 V and Vdd = 2.5 V)	
Output Voltage Low	VOL	-	-	10%	Vdd	IOL = 4 mA (Vdd = 3.3 V) IOL = 3 mA (Vdd = 2.8 V and Vdd = 2.5 V)	
Output Load	Ld	-	-	15	pF	At 125MHz and max supply voltage. Contact SiTime for higher output load option	
Input Voltage High	VIH	70%	-	-	Vdd	Pin 1, OE or ST	
Input Voltage Low	VIL	_	_	30%	Vdd	Pin 1, OE or ST	
Startup Time	T_start	_	_	10	ms	Measured from the time Vdd reaches its rated minimum value	
Resume Time	T_resume	_	3.0	3.8	ms	Measured from the time ST pin crosses 50% threshold	
RMS Period Jitter	T_jitt	-	-	4.5	ps	f = 125 MHz, Vdd = 2.5 V, 2.8 V or 3.3 V	
RMS Phase Jitter (random)	T_phj	-	0.5	_	ps	f = 125 MHz, Integration bandwidth = 900 kHz to 7.5 MHz, VDD = 2.5 V, 2.8 V, or 3.3 V	

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### ■ Specifications (Cont.)

### **Pin Description Tables**

Pin #1 Functionality OE		
H or Open: specified frequency output		
L: output is high impedance		
ST		
H or Open: specified frequency output		
L: output is low level (weak pull down). Oscillation stops		

Pin Map				
Pin	Connection			
1	OE/ST			
2	GND			
3	CLK			
4	VDD			

#### **Absolute Maximum Table**

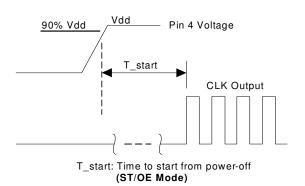
Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

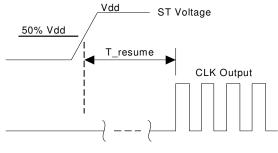
Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	
VDD	-0.5	4	V
Electrostatic Discharge	_	2000	V
Theta JA (with copper plane on VDD and GND)	-	75	°C/W
Theta JC (with PCB traces of 0.010 inch to all pins)	_	24	°C/W
Soldering Temperature (follow standard Pb free soldering guidelines)	-	260	∞
Number of Program Writes	-	1	NA
Program Retention over -40 to 125 °C, Process, VDD (0 to 3.65 V)	1,000+	-	years

### **Environmental Compliance**

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002
Mechanical Vibration	MIL-STD-883F, Method 2007
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensitivity Level	MSL1 @ 260℃

### Startup and Resume Timing Diagram



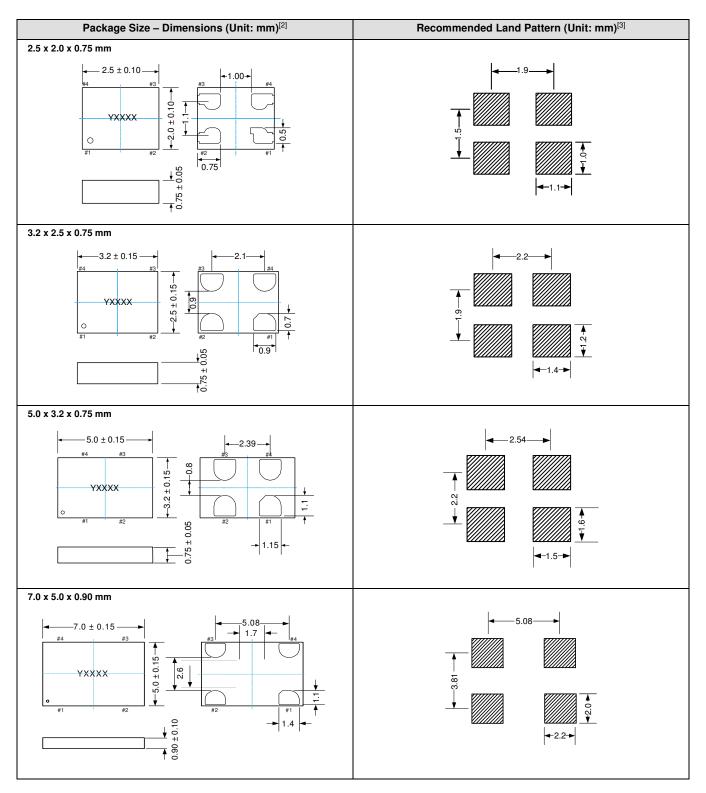


T\_resume: Time to resume from ST (ST Mode Only)

# Low Power Oscillator for High Frequency Applications



### ■ Dimensions and Land Patterns

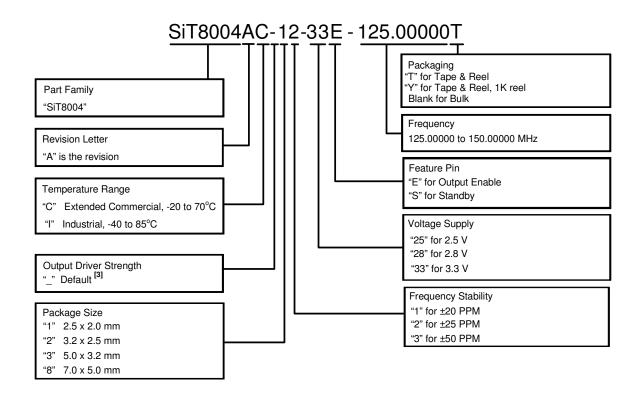


- Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
   A capacitor of value 0.1 μF between Vdd and GND is recommended.

### Low Power Oscillator for High Frequency Applications



■ Part No. Guide = How to Order



#### Note:

3. Contact SiTime for different drive strength options for driving higher loads or reducing EMI.

### Frequency Stability vs. Temperature Range Options

Frequency	Temperature	Supply Voltage		
Stability (PPM)	Range	2.5 V	2.8 V	3.3 V
±20	C (-20 to +70 °C)	<b>√</b>	<b>√</b>	✓
	I (-40 to +85 °C)	-	-	-
±25	C (-20 to +70 °C) I (-40 to +85 °C)	<b>✓</b>	<b>✓</b>	<b>√</b>
±50	C (-20 to +70 °C) I (-40 to +85 °C)	✓	✓	✓

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### SiTime:

<u>SiT8004AC-23-25E-150.00000Y</u> <u>SiT8004AC-83-33E-125.00000Y</u> <u>SiT8004AC-83-33E-125.00000T</u> <u>SiT8004AC-23-25E-125.00000X</u> SIT8004AC-83-33E-125.00T SIT8004AC-83-33E-125.00Y